



400V DUAL NPN MEDIUM POWER TRANSISTORS IN PowerDI3333-8

Features

- Dual NPN with Common-Collector
- BV_{CEO} > 400V
- I_C = 0.5A Continuous Collector Current
- · Configurable as NPN Darlington Pair
- Low Saturation Voltage V_{CE(SAT)} < 175mV @ 500mA
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

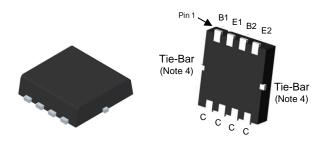
Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.072 grams (Approximate)

Applications

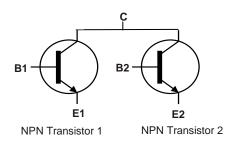
- Power Management
- High Voltage Start-Up Switch
- DC-DC Converters

PowerDI3333-8 (Type UXB)



Top View Bottom View

Dual NPN with Common-Collector



Equivalent Circuit

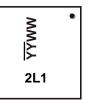
Ordering Information (Note 5)

Ī	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	ZXTN08400BNS-7	Standard	2L1	7	12	2,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Tie-bars are internally connected to the Common-Collector. They do not need to be externally connected.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



2L1 = Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 19 for 2019)

WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	450	V
Collector-Emitter Voltage (Forward Blocking)	V _{CEX}	450	V
Collector-Emitter Voltage	V _{CEO}	400	V
Emitter-Collector Voltage (Reverse Blocking)	V _{ECO}	6	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	0.5	Α
Peak Pulse Current	I _{CM}	1	Α
Base Current	I _B	0.2	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 6)		P _D	0.83	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	150	°C/W
Total Power Dissipation (Note 7)		P _D	1.83	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	R _{0JA}	68	°C/W
Thermal Resistance, Junction to Lead (Note 8)	$R_{\theta JL}$	19	C/VV	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

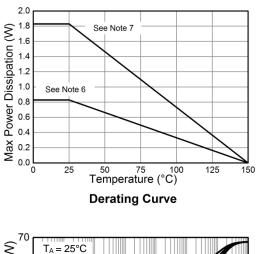
ESD Ratings (Note 9)

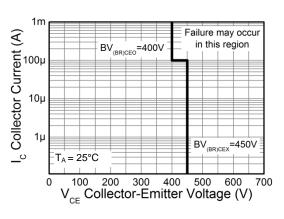
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

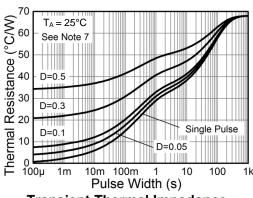
- Device mounted on FR-4 PCB board, with minimum recommended pad layout, single sided.
 Device mounted on FR-4 substrate PCB board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
 Thermal resistance from junction to soldering point (on the collector pads).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

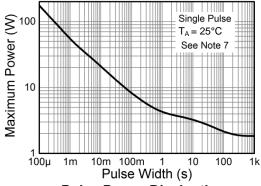


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation

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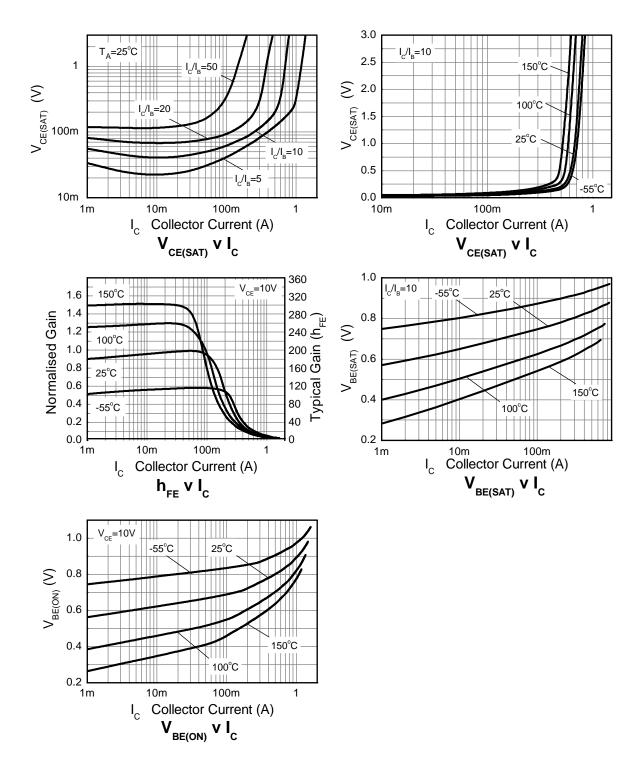
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS	•					•
Collector-Base Breakdown Voltage	BV _{CBO}	450	550	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Forward Blocking)	BV _{CEX}	450	550	_	V	$I_C = 100\mu A$, $R_{BE} \le 1k\Omega$ or -1V < V _{BE} < 0.25V
Collector-Emitter Breakdown Voltage (Base Open) (Note 10)	BV_CEO	400	500	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.1		V	$I_E = 100\mu A$
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV_{ECX}	6	8	_	V	$I_E = 100\mu A$, $R_{BC} \le 1k\Omega$ or -0.25V < $V_{BC} < 0.25V$
Emitter-Collector Breakdown Voltage (Base Open)	BV _{ECO}	6	8.5	_	V	I _E = 100μA
Collector-Base Cutoff Current			<1	50	nA	V _{CB} = 360V
Collector-Base Cutoff Current	I _{CBO}	_	_	20	μA	V _{CB} = 360V, T _A = +100°C
Collector-Emitter Cutoff Current	I _{CEX}	_	<1	100	nA	V _{CE} = 360V, R _{BE} ≤1kΩ -1V < V _{BE} < 0.25V
Emitter-Base Cutoff Current	I _{EBO}	_	<1	50	nA	V _{EB} = 5.6V
ON CHARACTERISTICS (Note 10)						
	h _{FE}	90	165			$I_C = 1$ mA, $V_{CE} = 5$ V
Static Forward Current Transfer Ratio		100	180	300	_	$I_{C} = 50 \text{mA}, V_{CE} = 5 \text{V}$
		10	20			I _C = 500mA, V _{CE} = 5V
			70	85		$I_C = 20$ mA, $I_B = 1$ mA
Collector-Emitter Saturation Voltage	VCE(SAT)		50	70	mV	$I_{C} = 50 \text{mA}, I_{B} = 5 \text{mA}$
Collector-Emitter Saturation Voltage			120	170	IIIV	$I_C = 300 \text{mA}, I_B = 30 \text{mA}$
			125	175		IC = 500mA, IB = 100mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	865	950	mV	I _C = 500mA, I _B = 100mA
Base-Emitter On Voltage	$V_{BE(ON)}$	_	800	900	mV	$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$
SMALL SIGNAL CHARACTERISTICS (Note 10)						
Transition Frequency	f⊤	_	40	_	MHz	$I_C = 10$ mA, $V_{CE} = 20$ V, f = 20MHz
Output Capacitance	Сово	_	8	10	pF	$V_{CB} = 20V, f = 1MHz$
Delay Time	t _D	_	100	_	ns	V _{CC} = 100V,
Rise Time	t _R	_	52	_	ns	$I_C = 100 \text{mA},$
Storage Time	t _S	_	3122		ns	$I_{B1} = 10mA$
Fall Time	t _F	_	240	_	ns	$I_{B2} = -20 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

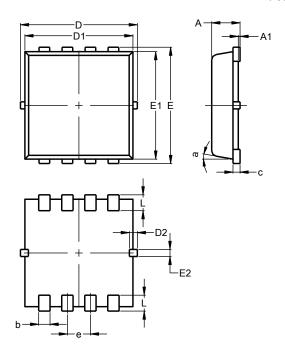




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UXB)

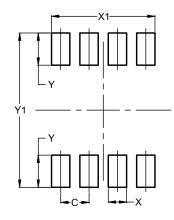


PowerDI3333-8						
(Type UXB)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	0.10	0.35	0.23			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	0.10	0.30	0.20			
e	-		0.65			
L	0.35	0.55	0.45			
а	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UXB)



Dimensions	Value (in mm)
C	0.650
Х	0.420
X1	2.370
Y	0.730
Y1	3.500

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking. Note:



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